MSA-0336

Cascadable Silicon Bipolar MMIC Amplifier

Data Sheet

Description

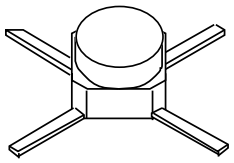
The MSA-0336 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a cost effective, microstrip package. This MMIC is designed for use as a general purpose 50 Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in industrial and military applications.

The MSA-series is fabricated using Avago's 10 GHz f_T, 25 GHz f_{MAX}, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

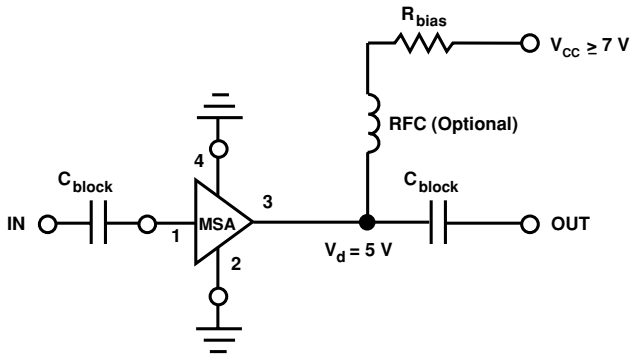
Features

- Cascadable 50 Ω Gain Block
- 3 dB Bandwidth: DC to 2.7 GHz
- 12.0 dB Typical Gain at 1.0 GHz
- 10.0 dBm Typical $P_{1\,dB}$ at 1.0 GHz
- Unconditionally Stable (k>1)
- Cost Effective Ceramic Microstrip Package

36 micro-X Package



Typical Biasing Configuration



MSA-0336 Absolute Maximum Ratings

Parameter	Absolute Maximum[1]
Device Current	80 mA
Power Dissipation[2,3]	425 mW
RF Input Power	+13 dBm
Junction Temperature	150°C
Storage Temperature[4]	–65 to 150°C

Thermal Resistance[2,5]:
θ_{jc} = 150°C/W

Notes:
1. Permanent damage may occur if any of these limits are exceeded.
2. T_{CASE} = 25°C.
3. Derate at 6.7 mW/°C for T_C > 136°C.
4. Storage above +150°C may tarnish the leads of this package making it difficult to solder into a circuit.
5. The small spot size of this technique results in a higher, though more accurate determination of θ_{jc} than do alternate methods.

Electrical Specifications[1], T_A = 25°C

Symbol	Parameters and Test Conditions: I_d = 35 mA, Z_O = 50 Ω		Units	Min.	Typ.	Max.
G_P	Power Gain ($\|S_{21}\|^2$)	f = 0.1 GHz	dB	11.5	12.5	13.5
ΔG_P	Gain Flatness	f = 0.1 to 1.6 GHz	dB		±0.6	±1.0
$f_{3\ dB}$	3 dB Bandwidth		GHz		2.7	
VSWR	Input VSWR	f = 0.1 to 3.0 GHz			1.6:1	
	Output VSWR	f = 0.1 to 3.0 GHz			1.7:1	
NF	50 Ω Noise Figure	f = 1.0 GHz	dB		6.0	
$P_{1\ dB}$	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm		10.0	
IP_3	Third Order Intercept Point	f = 1.0 GHz	dBm		23.0	
t_D	Group Delay	f = 1.0 GHz	psec		125	
V_d	Device Voltage		V	4.5	5.0	5.5
dV/dT	Device Voltage Temperature Coefficient		mV/°C		–8.0	

Notes:
1. The recommended operating current range for this device is 20 to 50 mA. Typical performance as a function of current is on the following page.

Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0336-BLKG	100	Bulk
MSA-0336-TR1G	1000	7" Reel

MSA-0336 Typical Scattering Parameters (Z_0 = 50 Ω, T_A = 25°C, I_d = 35 mA)

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	.05	177	12.6	4.25	175	–18.6	.118	1	.17	–8
0.2	.05	170	12.5	4.24	170	–18.3	.121	2	.17	–17
0.4	.04	161	12.5	4.20	160	–18.3	.122	3	.17	–33
0.6	.04	156	12.4	4.15	151	–18.3	.121	5	.18	–47
0.8	.03	149	12.2	4.09	142	–17.9	.128	8	.19	–61
1.0	.02	154	12.1	4.02	132	–17.6	.131	9	.20	–73
1.5	.03	–104	11.6	3.79	109	–16.8	.145	13	.20	–102
2.0	.08	–136	10.9	3.49	87	–15.7	.164	11	.21	–133
2.5	.14	–157	10.0	3.16	71	–14.9	.180	13	.23	–155
3.0	.21	–176	9.0	2.81	53	–14.6	.187	8	.24	–173
3.5	.27	170	7.9	2.49	36	–13.9	.202	4	.25	178
4.0	.31	157	6.9	2.20	20	–13.6	.209	–1	.24	177
5.0	.37	125	4.9	1.76	–10	–12.9	.226	–12	.20	165
6.0	.51	87	2.8	1.38	–38	–12.8	.230	–25	.22	130

Typical Performance, T_A = 25°C

(unless otherwise noted)

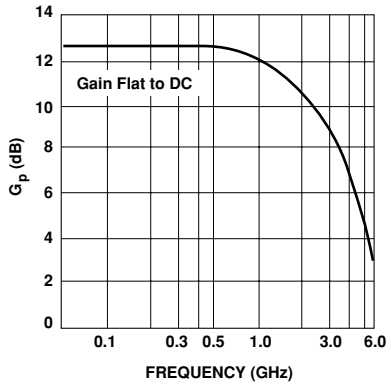


Figure 1. Typical Power Gain vs. Frequency, T_A = 25°C, I_d = 35 mA.

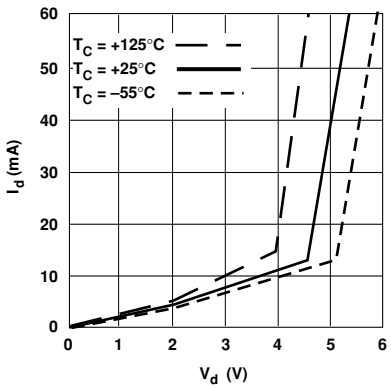


Figure 2. Device Current vs. Voltage.

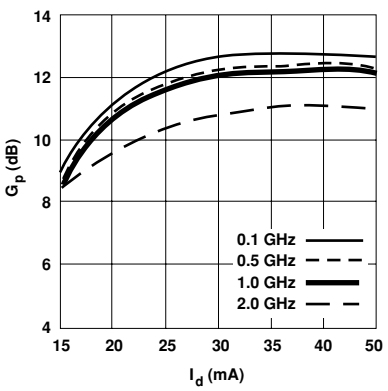


Figure 3. Power Gain vs. Current.

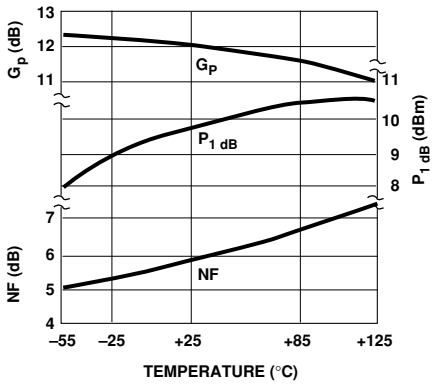


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Mounting Surface Temperature, f = 1.0 GHz, I_d = 35 mA.

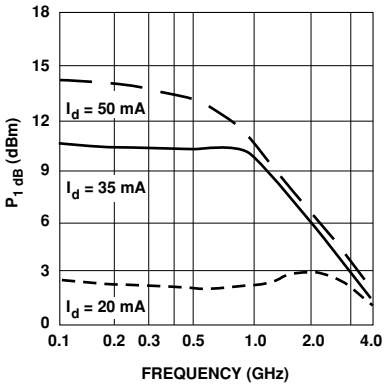


Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.

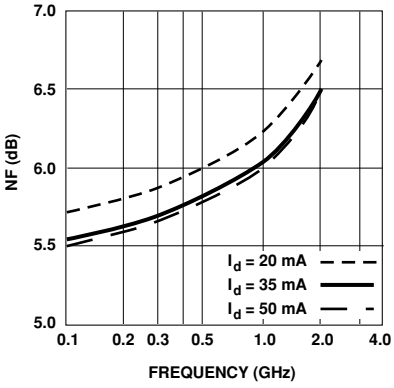
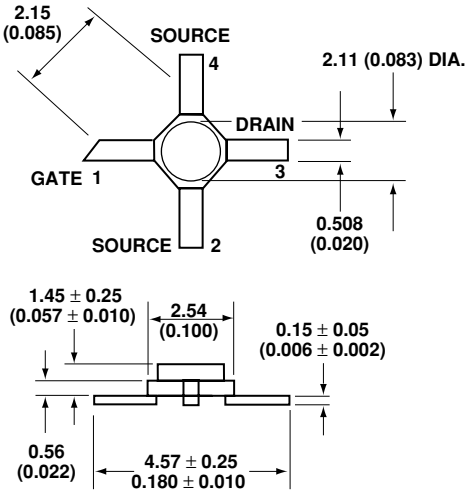


Figure 6. Noise Figure vs. Frequency.

36 micro-X Package Dimensions



Notes:
1. **Dimensions are in millimeters (inches)**
2. **Tolerances: in .xxx = ± 0.005**
   mm .xx = ± 0.13

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